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NCE7075K

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE7075K uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. It can be used in a wide variety of applications.

General Features

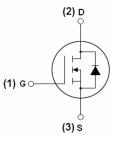
- V_{DS} =70V,I_D =75A $R_{DS(ON)} < 13m\Omega$ @ $V_{GS}=10V$ (Typ:10.5m Ω)
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% AVds TESTED!



Schematic diagram



Marking and pin assignment



TO-252-2L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE7075K	NCE7075K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	70	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	75	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	50	Α
Pulsed Drain Current	I _{DM}	300	Α
Maximum Power Dissipation	P _D	110	W
Derating factor		0.73	W /℃
Single pulse avalanche energy (Note 5)	E _{AS}	450	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$ C

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Thermal Characteristic

Electrical Characteristics (T_C=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	70	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =70V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	On Characteristics (Note 3)					
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	2	3	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	10.5	13	mΩ
Forward Transconductance	g FS	V _{DS} =25V,I _D =30A	20	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	\/ -25\/\/ -0\/	-	2350	-	PF
Output Capacitance	C _{oss}	V_{DS} =25V, V_{GS} =0V, F=1.0MHz	-	237	-	PF
Reverse Transfer Capacitance	C _{rss}	T = 1.0WH12	-	205	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	16	-	nS
Turn-on Rise Time	t _r	V_{DD} =30 V , I_D =2 A , R_L =15 Ω	-	10	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =2.5 Ω	-	45	-	nS
Turn-Off Fall Time	t _f		-	12	-	nS
Total Gate Charge	Qg	V _{DS} =30V,I _D =30A,	-	50	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=30V,I_{D}=30A,$ $V_{GS}=10V$	-	12	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} -10V	-	16	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =75A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	75	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =75A	-	28		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	49		nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

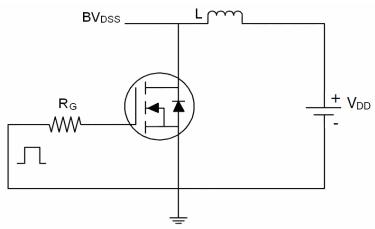
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}$ C,V_{DD}=35V,V_G=10V,L=0.5mH,Rg=25 Ω

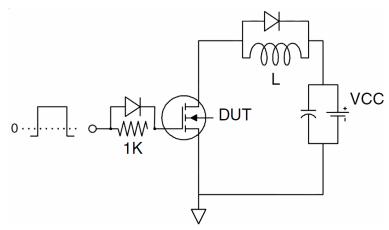


Test Circuit

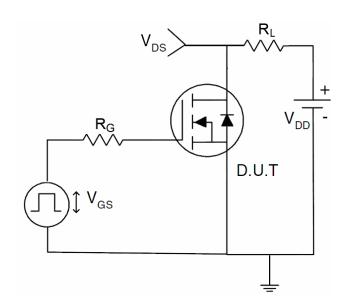
1) E_{AS} test Circuit

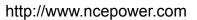


2) Gate charge test Circuit



3) Switch Time Test Circuit









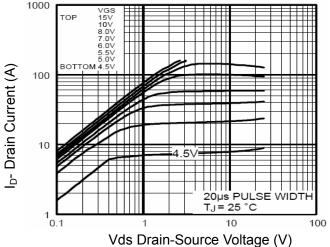


Figure 1 Output Characteristics

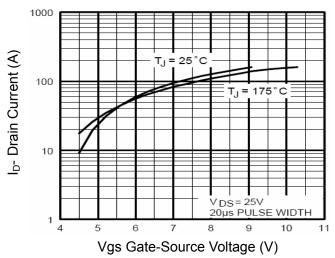


Figure 2 Transfer Characteristics

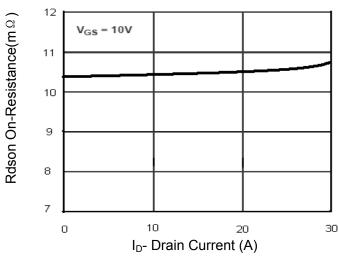


Figure 3 Rdson- Drain Current

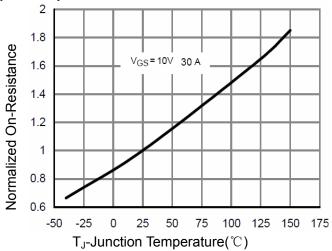


Figure 4 Rdson-JunctionTemperature

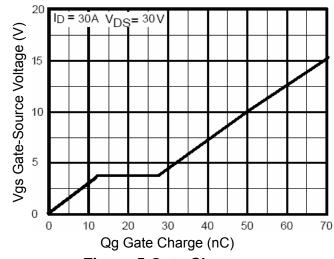


Figure 5 Gate Charge

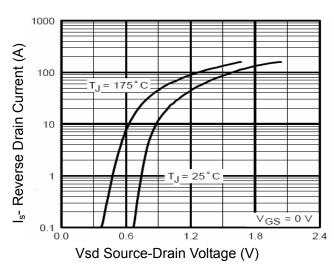


Figure 6 Source- Drain Diode Forward



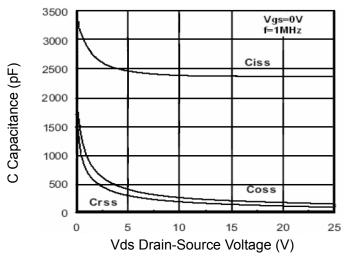


Figure 7 Capacitance vs Vds

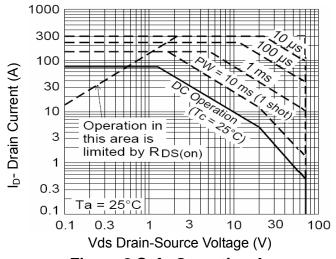


Figure 8 Safe Operation Area

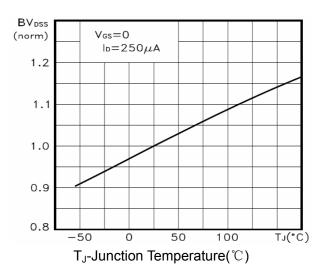


Figure 9 BV_{DSS} vs Junction Temperature

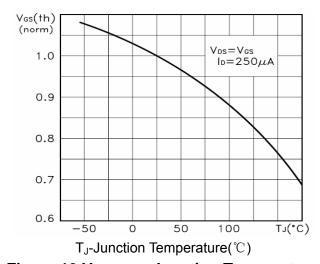


Figure 10 V_{GS(th)} vs Junction Temperature

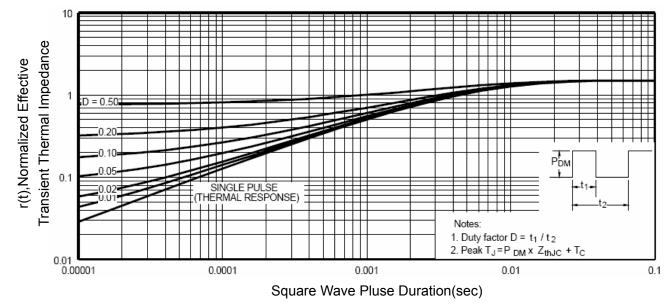


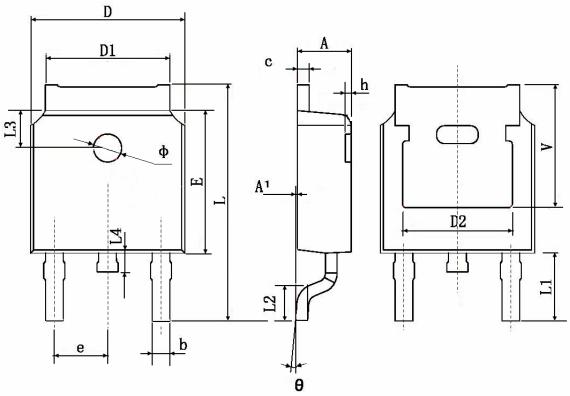
Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-252 Package Information



Cumbal	Dimensions In Millimeters		Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
A	2.200	2.400	0.087	0.094		
A1	0.000	0.127	0.000	0.005		
b	0.660	0.860	0.026	0.034		
С	0.460	0.580	0.018	0.023		
D	6.500	6.700	0.256	0.264		
D1	5.100	5.460	0.201	0.215		
D2	4.8	330 TYP.	0.190 TYP.			
Е	6.000	6.200	0.236	0.244		
е	2.186	2.386	0.086	0.094		
L	9.800	10.400	0.386	0.409		
L1	2.90	0 TYP.	0.114 TYP.			
L2	1.400	1.700	0.055	0.067		
L3	1.60	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039		
Ф	1.100	1.300	0.043	0.051		
θ	0°	8°	0°	8°		
h	0.000	0.300	0.000	0.012		
V	5.35	0 TYP.	0.211 TYP.			



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